

## 1. General description

High voltage, high speed, planar passivated NPN power switching transistor with integrated anti-parallel emitter-collector diode in a SOT54 (TO-92) plastic package.

## 2. Features and benefits

- High typical DC current gain
- Fast switching
- High voltage capability
- Integrated anti-parallel E-C diode

## 3. Applications

- Compact fluorescent lamps (CFL)
- Low power electronic lighting ballasts
- Off-line self-oscillating power supplies (SOPS) for battery charging

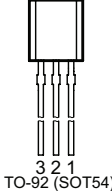
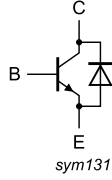
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit
<b>Absolute maximum rating</b>						
$V_{CESM}$	collector-emitter peak voltage	$V_{BE} = 0 \text{ V}$	700			V
$I_C$	collector current	DC	1.5			A
$P_{tot}$	total power dissipation	$T_{lead} \leq 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 1</a>	2.1			W
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$h_{FE}$	DC current gain	$I_C = 0.5 \text{ A}$ ; $V_{CE} = 2 \text{ V}$ ; $T_j = 25 \text{ }^\circ\text{C}$	8	17	25	

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B	base	 <p>TO-92 (SOT54)</p>	 <p>sym131</p>
2	C	collector		
3	E	emitter		

## 6. Ordering information

Table 3. Ordering information

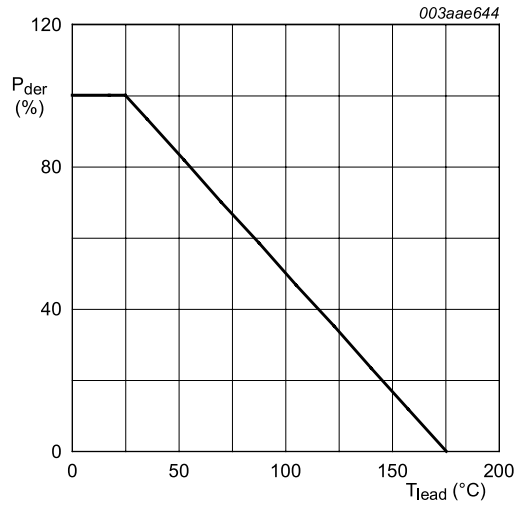
Type number	Package		
	Name	Description	Version
PHD13003C	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54

## 7. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{CESM}$	collector-emitter peak voltage	$V_{BE} = 0 \text{ V}$	700	V
$V_{CBO}$	collector-base voltage	$I_E = 0 \text{ A}$	700	V
$V_{CEO}$	collector-emitter voltage	$I_B = 0 \text{ A}$	400	V
$I_C$	collector current	DC	1.5	A
$I_{CM}$	peak collector current		3	A
$I_B$	base current	DC	0.75	A
$I_{BM}$	peak base current		1.5	A
$P_{tot}$	total power dissipation	$T_{lead} \leq 25 \text{ °C}$ ; <a href="#">Fig. 1</a>	2.1	W
$T_{stg}$	storage temperature		-65 to 150	°C
$T_j$	junction temperature		150	°C
$V_{EBO}$	emitter-base voltage	$I_C = 0 \text{ A}$ ; $I(\text{Emitter}) = 10 \text{ mA}$	9	V



$$P_{der}(\%) = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

Fig. 1. Normalized total power dissipation as a function of lead temperature

### 8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	<a href="#">Fig. 2</a>	-	-	60	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air; printed-circuit board mounted; lead length = 4 mm	-	150	-	K/W

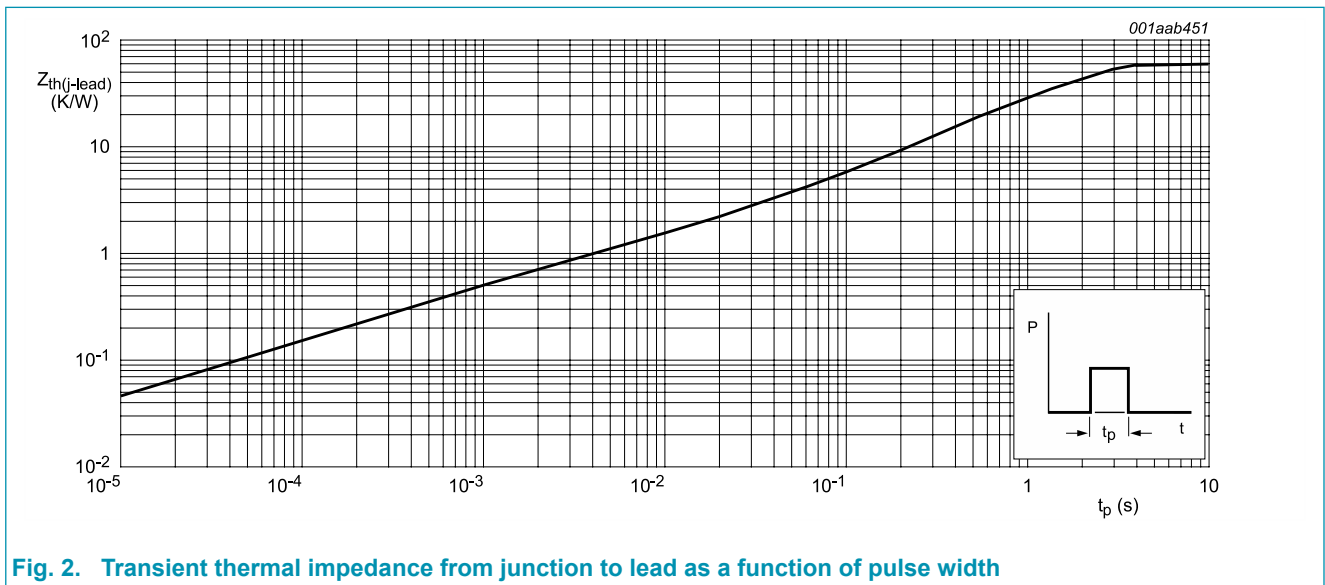


Fig. 2. Transient thermal impedance from junction to lead as a function of pulse width

## 9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$I_{CES}$	collector-emitter cut-off current	$V_{BE} = 0\text{ V}; V_{CE} = 700\text{ V}$	-	-	1	mA
		$V_{BE} = 0\text{ V}; V_{CE} = 700\text{ V}; T_j = 100^\circ\text{C}$	-	-	5	mA
$I_{CEO}$	collector-emitter cut-off current	$V_{CE} = 400\text{ V}; I_B = 0\text{ A}; T_{lead} = 25^\circ\text{C}$	-	-	0.1	mA
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 9\text{ V}; I_C = 0\text{ A}; T_{lead} = 25^\circ\text{C}$	-	-	1	mA
$V_{CE0sus}$	collector-emitter sustaining voltage	$I_B = 0\text{ A}; I_C = 1\text{ mA}; L_C = 25\text{ mH}; T_{lead} = 25^\circ\text{C}$ ; <a href="#">Fig. 3</a> ; <a href="#">Fig. 4</a>	400	-	-	V
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 0.5\text{ A}; I_B = 0.1\text{ A}; T_{lead} = 25^\circ\text{C}$	-	-	0.5	V
		$I_C = 1\text{ A}; I_B = 0.25\text{ A}; T_{lead} = 25^\circ\text{C}$	-	-	1	V
		$I_C = 1.5\text{ A}; I_B = 0.5\text{ A}; T_{lead} = 25^\circ\text{C}$	-	-	1.5	V
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 0.5\text{ A}; I_B = 0.1\text{ A}; T_{lead} = 25^\circ\text{C}$	-	-	1	V
		$I_C = 1\text{ A}; I_B = 0.25\text{ A}; T_{lead} = 25^\circ\text{C}$	-	-	1.2	V
$V_F$	forward voltage	$I_F = 0.5\text{ A}; T_j = 25^\circ\text{C}$	-	-	1.5	V
$h_{FE}$	DC current gain	$I_C = 0.5\text{ A}; V_{CE} = 2\text{ V}; T_j = 25^\circ\text{C}$	8	17	25	
		$I_C = 1\text{ A}; V_{CE} = 2\text{ V}; T_j = 25^\circ\text{C}$	5	9	15	
<b>Dynamic characteristics</b>						
$t_{on}$	turn-on time	$I_C = 1\text{ A}; I_{Bon} = 0.2\text{ A}; I_{Boff} = -0.2\text{ A}; R_L = 75\ \Omega; T_{lead} = 25^\circ\text{C}$ ; resistive load; <a href="#">Fig. 5</a> ; <a href="#">Fig. 6</a>	-	-	1	$\mu\text{s}$
$t_s$	storage time	$I_C = 1\text{ A}; I_{Bon} = 0.2\text{ A}; I_{Boff} = -0.2\text{ A}; R_L = 75\ \Omega; T_{lead} = 25^\circ\text{C}$ ; resistive load; <a href="#">Fig. 5</a> ; <a href="#">Fig. 6</a>	-	-	4	$\mu\text{s}$
		$I_C = 1\text{ A}; I_{Bon} = 0.2\text{ A}; V_{BB} = -5\text{ V}; L_B = 1\ \mu\text{H}; T_{lead} = 25^\circ\text{C}$ ; inductive load; <a href="#">Fig. 7</a> ; <a href="#">Fig. 8</a>	-	0.8	-	$\mu\text{s}$
$t_f$	fall time	$I_C = 1\text{ A}; I_{Bon} = 0.2\text{ A}; I_{Boff} = -0.2\text{ A}; R_L = 75\ \Omega; T_{lead} = 25^\circ\text{C}$ ; resistive load; <a href="#">Fig. 5</a> ; <a href="#">Fig. 6</a>	-	-	0.7	$\mu\text{s}$
		$I_C = 0.5\text{ A}; I_{Bon} = 0.1\text{ A}; V_{BB} = -5\text{ V}; L_B = 1\ \mu\text{H}; T_{lead} = 25^\circ\text{C}$ ; inductive load; <a href="#">Fig. 7</a> ; <a href="#">Fig. 8</a>	-	0.1	-	$\mu\text{s}$

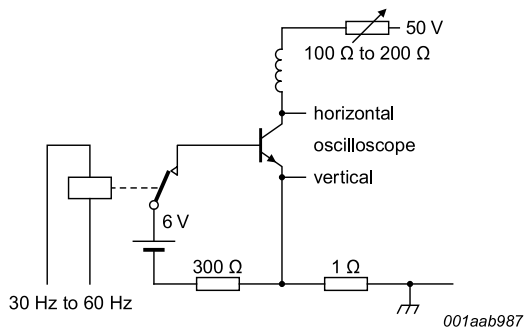


Fig. 3. Test circuit for collector-emitter sustaining voltage

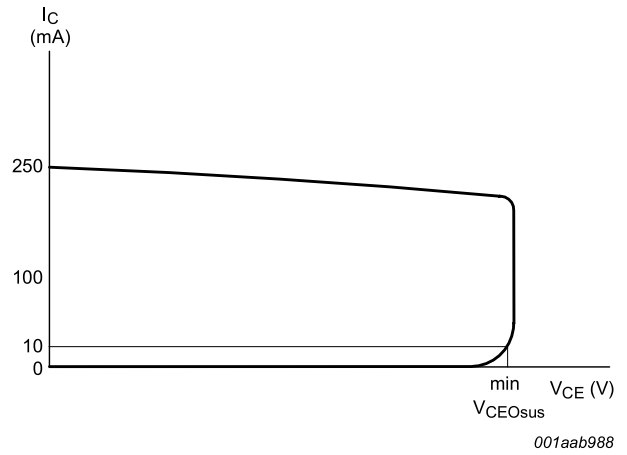
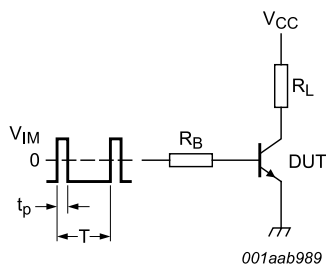


Fig. 4. Oscilloscope display for collector-emitter sustaining voltage test waveform



$V_{IM} = -6\text{ V to } +8\text{ V}$ ;  $V_{CC} = 250\text{ V}$ ;  $t_p = 20\text{ }\mu\text{s}$ ;  
 $\delta = t_p/T = 0.01$ .  
 $R_B$  and  $R_L$  calculated from  $I_{Con}$  and  $I_{Bon}$  requirements

Fig. 5. Test circuit for resistive load switching

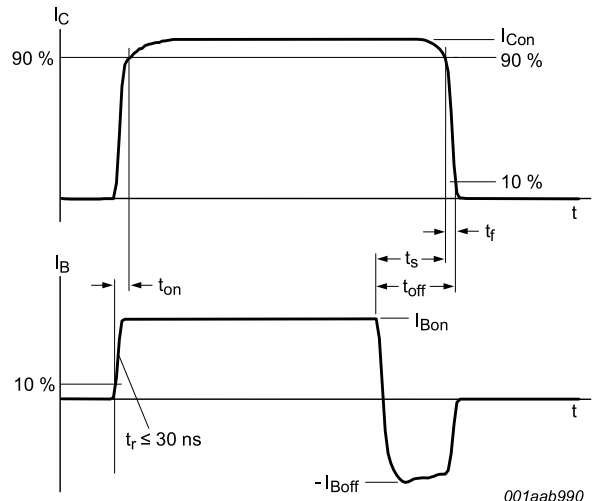
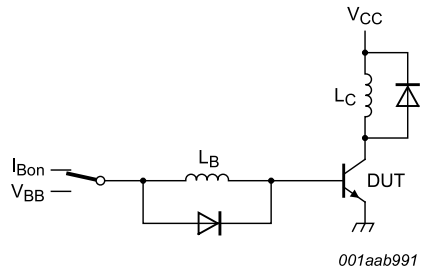


Fig. 6. Switching times waveforms for resistive load



$V_{CC} = 300\text{ V}; V_{BB} = -5\text{ V}; L_C = 200\ \mu\text{H}; L_B = 1\ \mu\text{H}.$

Fig. 7. Test circuit for inductive load switching

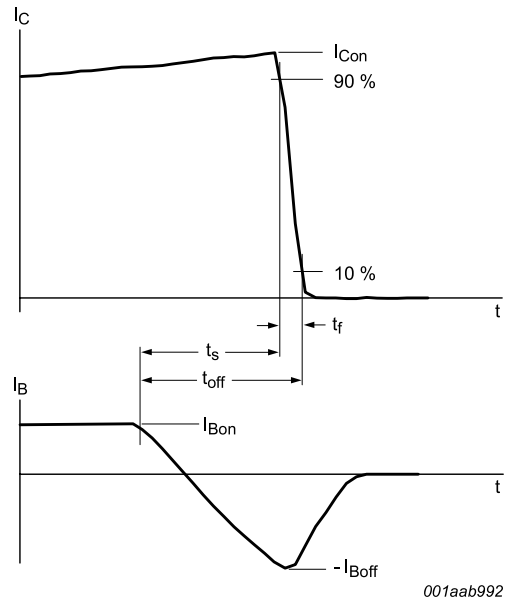
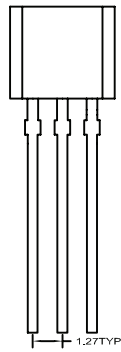


Fig. 8. Switching times waveforms for inductive load

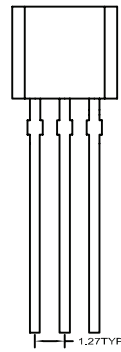
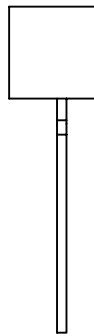


### 10. Package outline

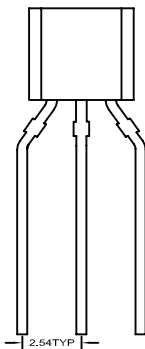
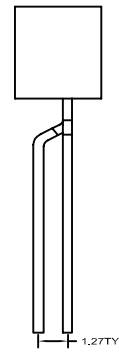
#### SOT54 PACKAGE OUTLINE



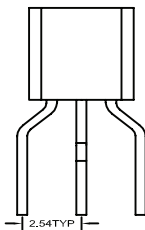
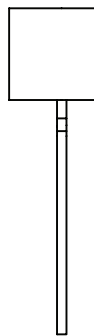
SOT54  
Bulk Pack - 412



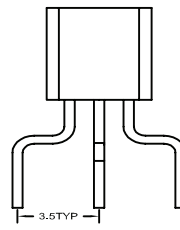
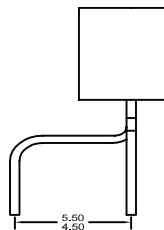
SOT54 LEADS ON CIRCLE  
Bulk Pack - 112



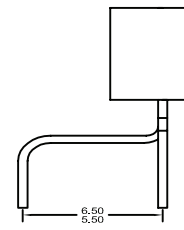
SOT54 WIDE PITCH  
Tape/ Reel Pack - 116  
Ammo Pack - 126



SOT54 LEAD BEND L01  
Bulk Pack - 412



SOT54 LEAD BEND L02  
Bulk Pack - 412



Remark: Detailed dimensions refer to POD drawing.

## 11. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PHD13003C v.2	20180224	Product data sheet	-	PHD13003C v.1
Modifications:	Change from NXP version to WeEn version			
PHD13003C v.1	20100729	Product data sheet	-	-

## 12. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Date of release: 29 May 2018

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